

AHCAL Activities in Tokyo

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CALICE AHCAL Main Meeting

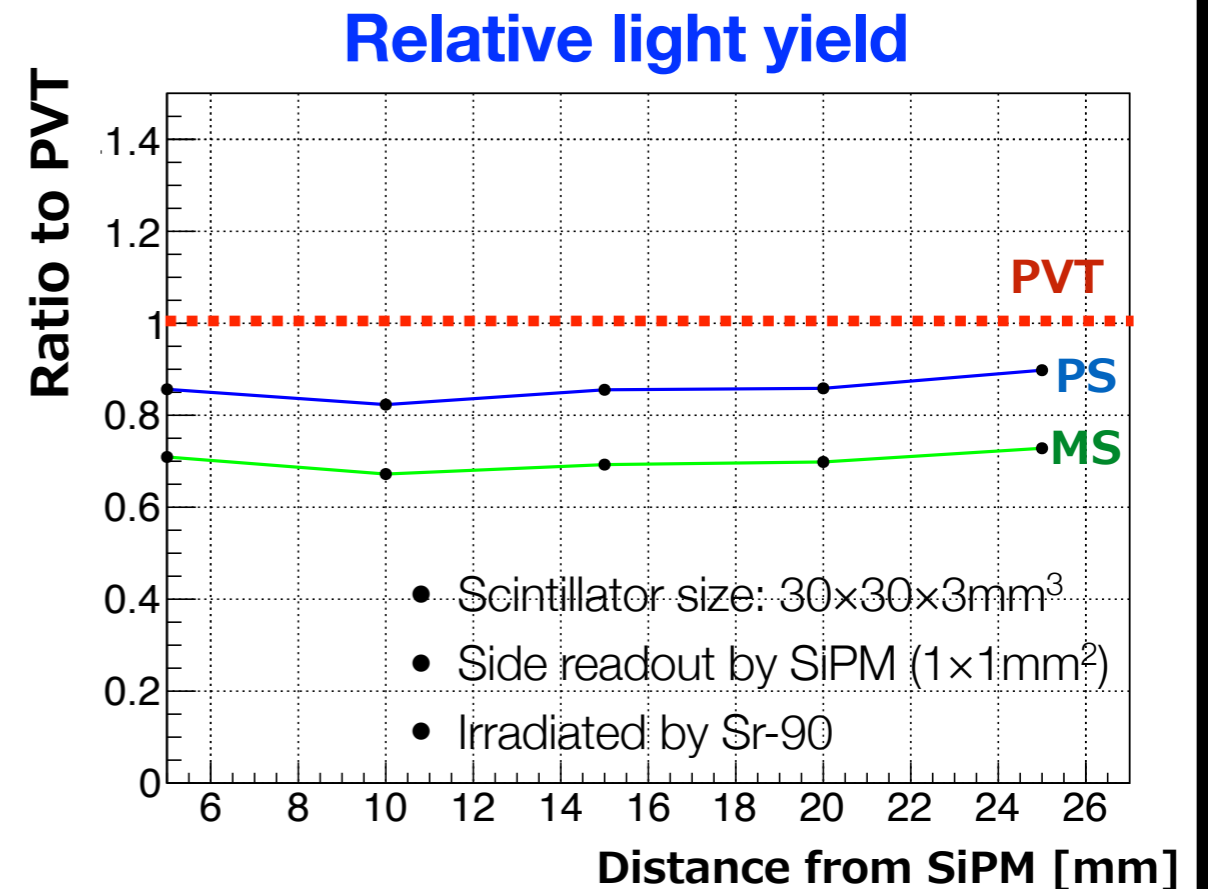
Dec. 10-11, 2015 DESY

Current Activities @Tokyo

- Scintillator material study
- New readout scheme for AHCAL scintillator tile
- Radiation hardness test

Scintillator Material Study: Reminder

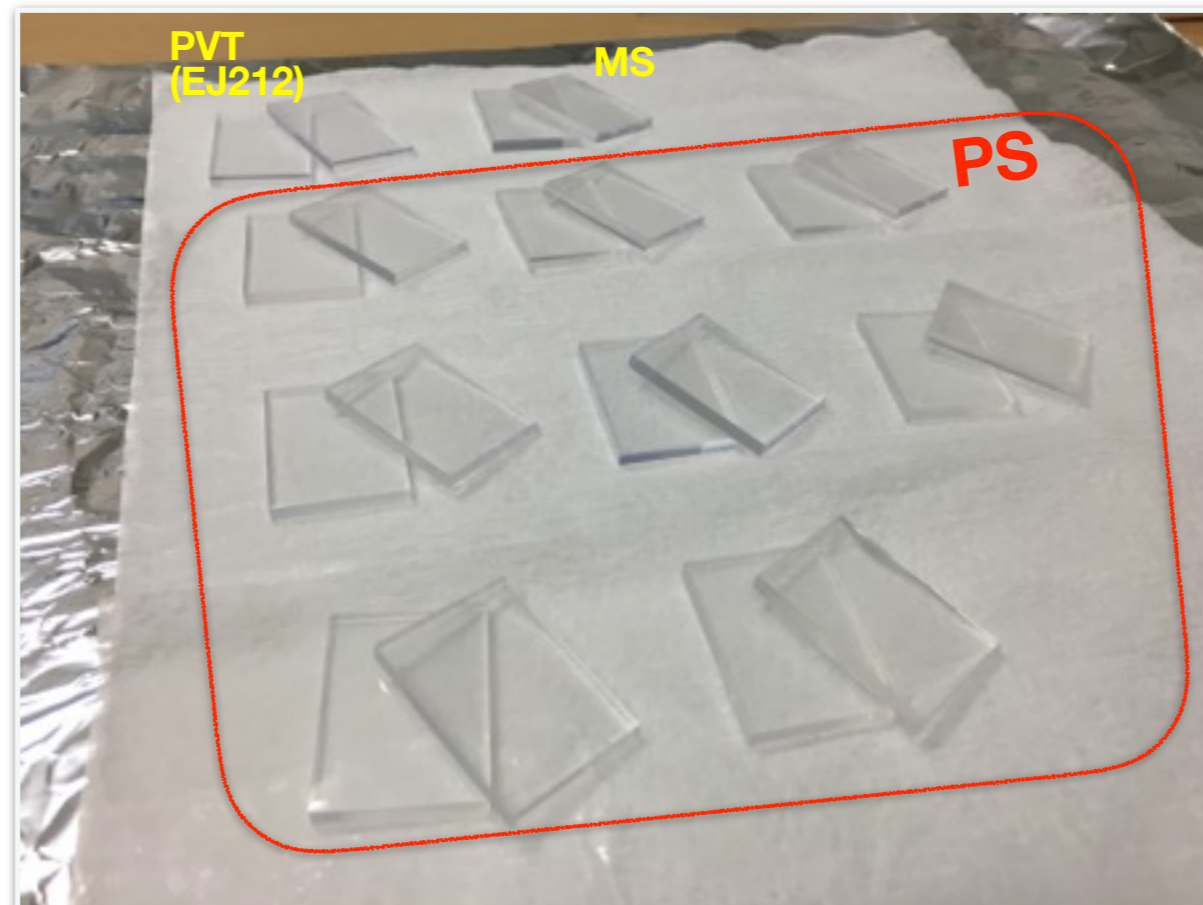
- Development of plastic scintillator material of better performance
- Base scintillator material candidates
 - Poly-vinyl toluene (PVT):
 - 😊 Higher light yield
 - 😞 Production (casting+machining) is cumbersome.
 - Polystyrene (PS), Estyrene-MS (MS)
 - 😐 Moderate light yield
 - 😊 Production (injection moulding) is easier.
- Light yield was measured with AHCAL tile configuration (30×30×3mm³).



- PVT shows the highest light yield (as expected).
- The light yield of PS is reasonably high (80-90% of PVT).
 - PS can be a good candidate material.
- No visible difference in position dependence.
 - No significant difference in both reflection and attenuation
- Further optimisation of scintillator materials is underway especially for PS/MS.

Scintillator Material Study

- Starting with optimisation of polystyrene(PS)-base scintillator
 - Primary fluorescent: **p-Terphenyl**
 - Secondary fluorescent: **POPOP**
- Test scintillator cells ($30 \times 22 \times 3 \text{mm}^3$) are produced with injection molding for different combinations of fluorescent concentrations to find the best production parameters.
- Performance is being measured.



New Scheme for AHCAL Tile Readout: Reminder

- A new AHCAL tile readout scheme, “four-corners readout”, is under study.
 - SiPMs are located at vertices of scintillator tiles and detect scintillation light from four adjacent tiles.
 - Tile hit is defined by taking a coincidence on four SiPMs belonging to the tile.
 - SiPM charge is split to hit tiles if shared by adjacent hit tiles.

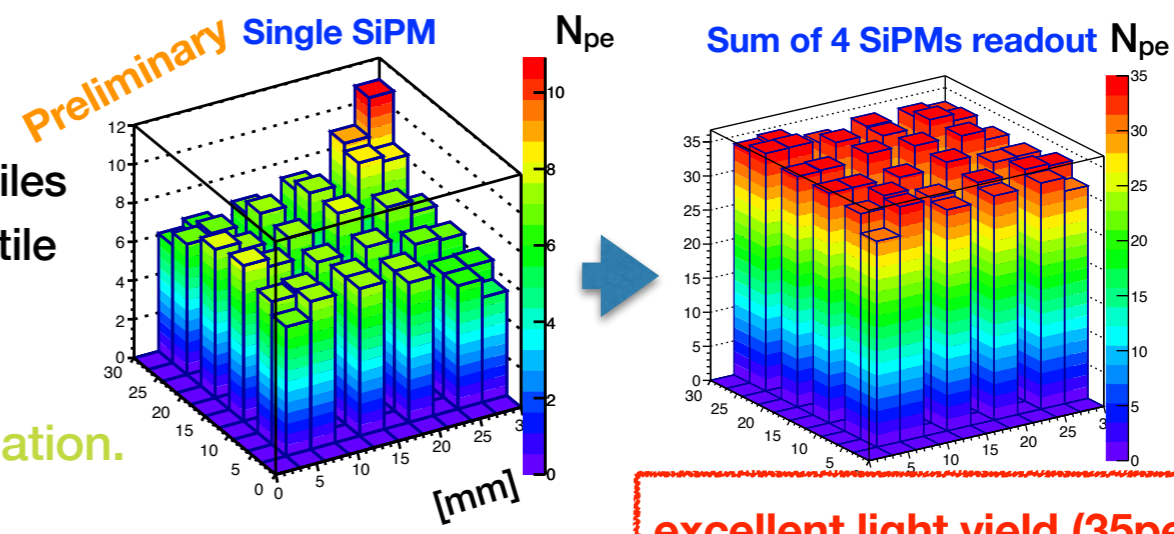
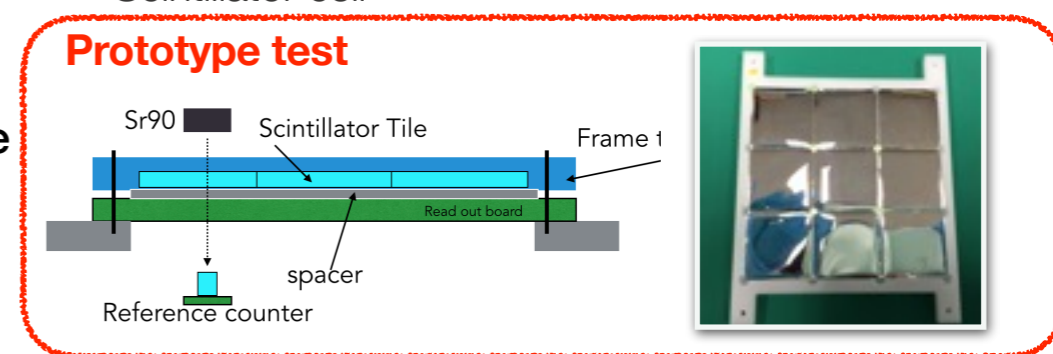
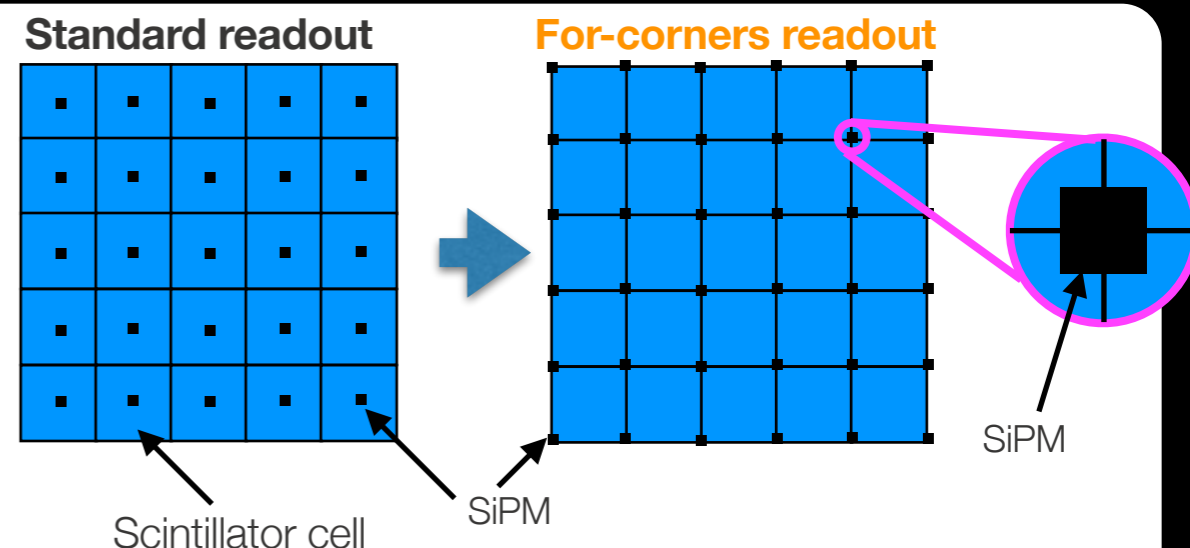
Advantages

- Reduced random noise by taking a coincidence over multiple SiPMs
- Excellent uniformity and light yield
- Still operational even with dead SiPM(s)
- Reduced number of calibration LEDs

Possible issues

- Cluster smearing due to fake hits
 - Intrinsic fake hit when the tile is surrounded by true hit tiles
 - Fake hit due to light leakage from neighbouring true hit tile
- How to split charge to adjacent hit tiles

- Effect of cluster smearing is being evaluated by MC simulation.
- Optical coupling btw tile and SiPM is being optimised.



excellent light yield (35pe)
uniformity ($\sigma \sim 3\%$)

Simulation Study with Four-corners Readout

- Simulation study on performance of AHCAL with four-corners readout

- Implementation of readout scheme

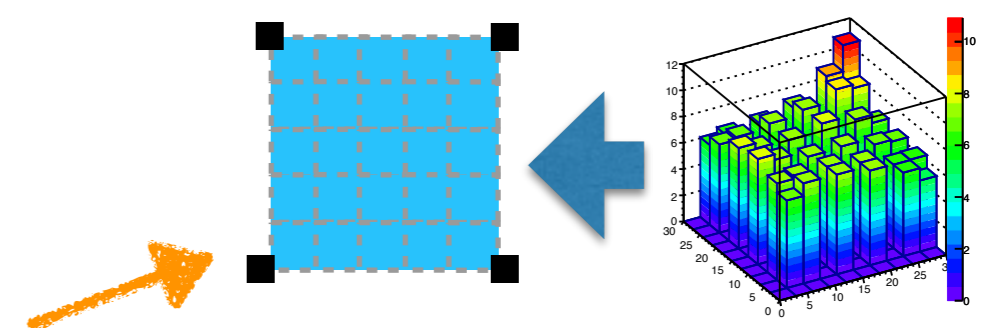
- Implemented in digitisation task of Marlin
- Properties of four-corners readout are implemented

- Position dependence in inside-tile response

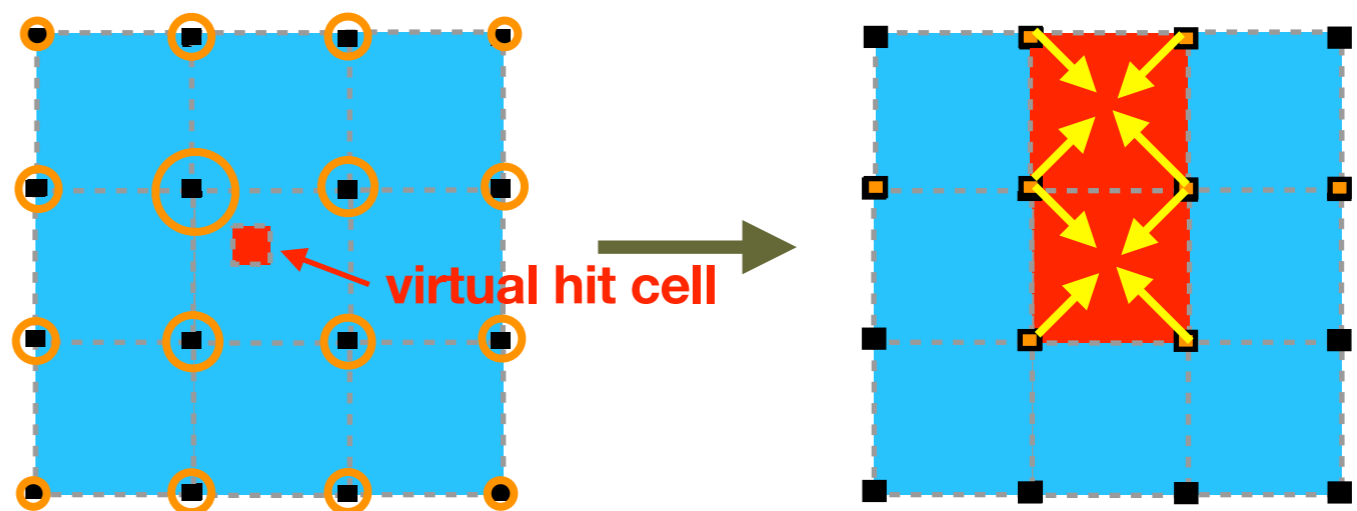
- Each tile is subdivided into 25 virtual cells ($6 \times 6 \text{mm}^2$ each) to include position-dependent SiPM output at both hit tile and neighbouring tile (light leakage)

- Taking coincidence to define tile hit

- Each SiPM is shared by four adjacent tiles. Summed SiPM charge is split into adjacent tiles.



- Implementation completed.



Generate charge at 16 surrounding SiPMs according to measured response and define tile hits

Split SiPM charge to neighbouring tiles

SiPM Radiation Hardness Study

- Radiation damage of SiPM

- Non-ionising process

- Lattice defect

- Additional energy level → increasing DCR/leak current

- Ionising process

- Damage in interface region btw insulation layer (SiO_2) and Si

- Modified E-field distribution

- Additional energy level → increasing DCR/leak current

- Radiation hardness of SiPM is not excellent as shown in previous studies.

- Expected dose @ ILC detector

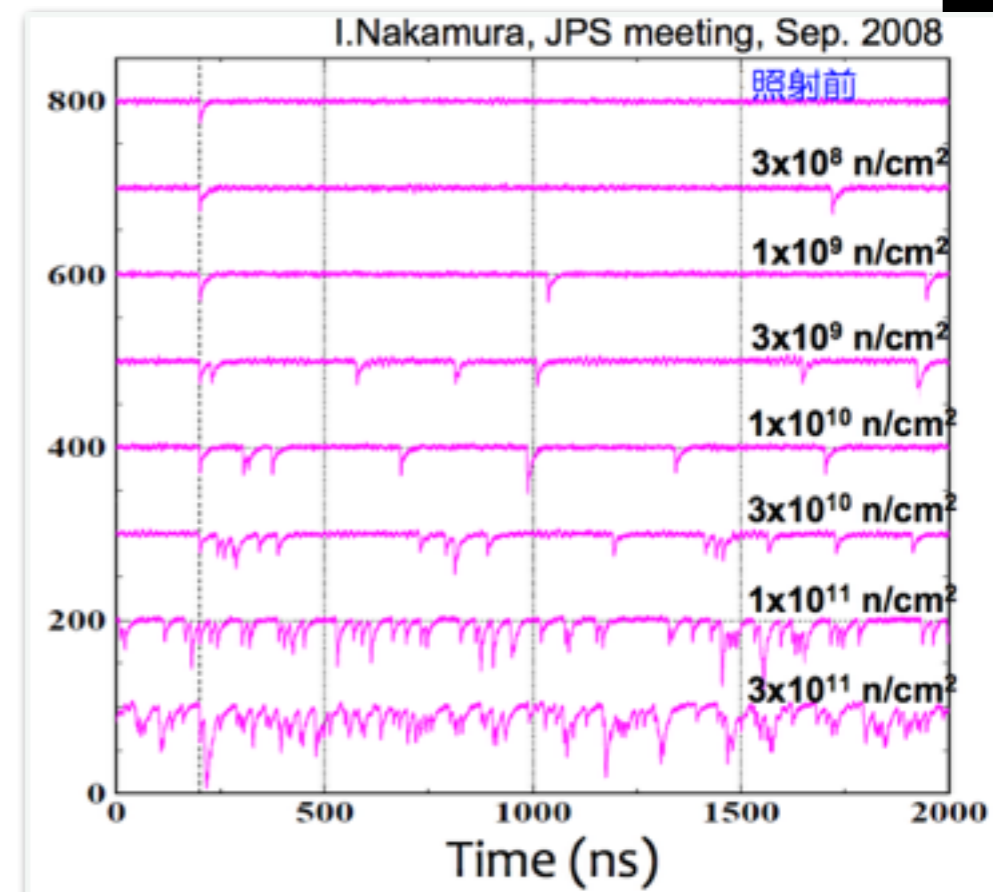
- ECAL barrel: $\sim 10^7$ n/cm²/10years (LC-DET-2007-013)

- ECAL endcap (CLIC): $< 2 \times 10^{11}$ n/cm²/10years (A. Sailer, CLICdp meeting on Oct. 2, 2013)

- Not crucial but might be an issue in extreme conditions

- Radiation hardness of new generation of MPPC might be different (hopefully better) since the layer/cell structure and material of insulation layer are modified.

- Also requested by Hamamatsu



Neutron Irradiation Test

- Tandem accelerator at Kobe University

- Neutron from nuclear reaction: ${}^9\text{Be} + d \rightarrow {}^{10}\text{Be} + n$
- Neutron yield: 10^8 n/sec

- Neutron fluence was measured by calibrated silicon diode (ELMA diode)

- Increase of leak current is calibrated by known flux.

- Irradiated samples

- MPPC (S10352-11-025C)

- $1 \times 1 \text{ mm}^2$, $25 \mu\text{m}$ -pixel
- Old version, no suppression on after-pulsing/cross-talk)

- MPPC (S12571-11-025C)

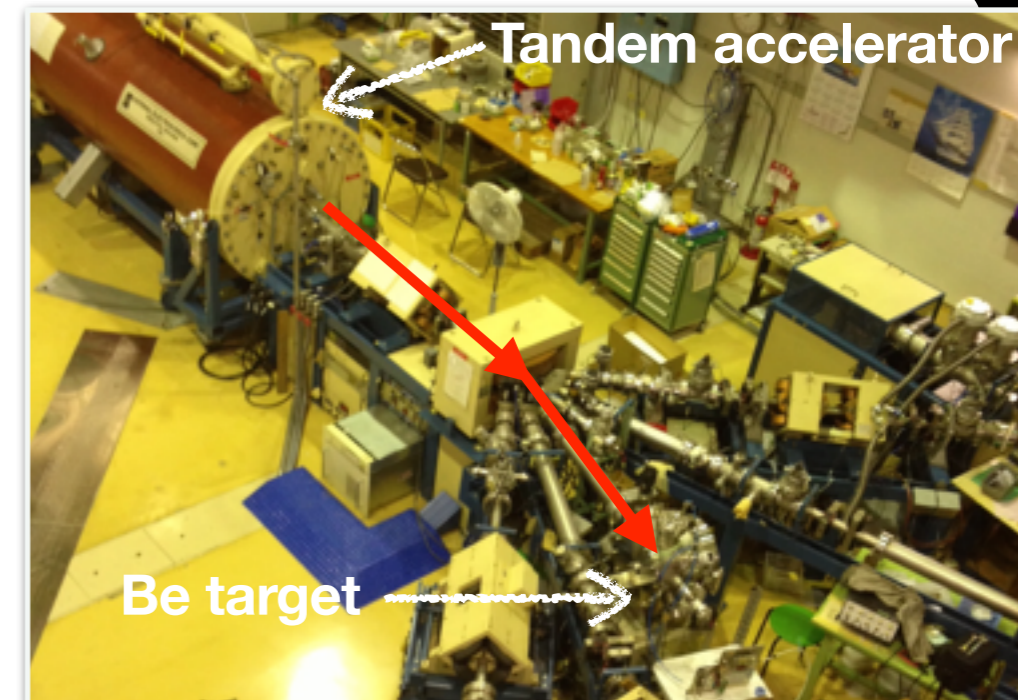
- $1 \times 1 \text{ mm}^2$, $25 \mu\text{m}$ -pixel
- Suppression on after-pulsing only, No suppression on cross-talk

- MPPC (S10943-3186(X))

- $6 \times 6 \text{ mm}^2$, $50 \mu\text{m}$ -pixel
- VUV-sensitive, developed for MEG
- Suppression on after-pulsing only, No suppression on cross-talk

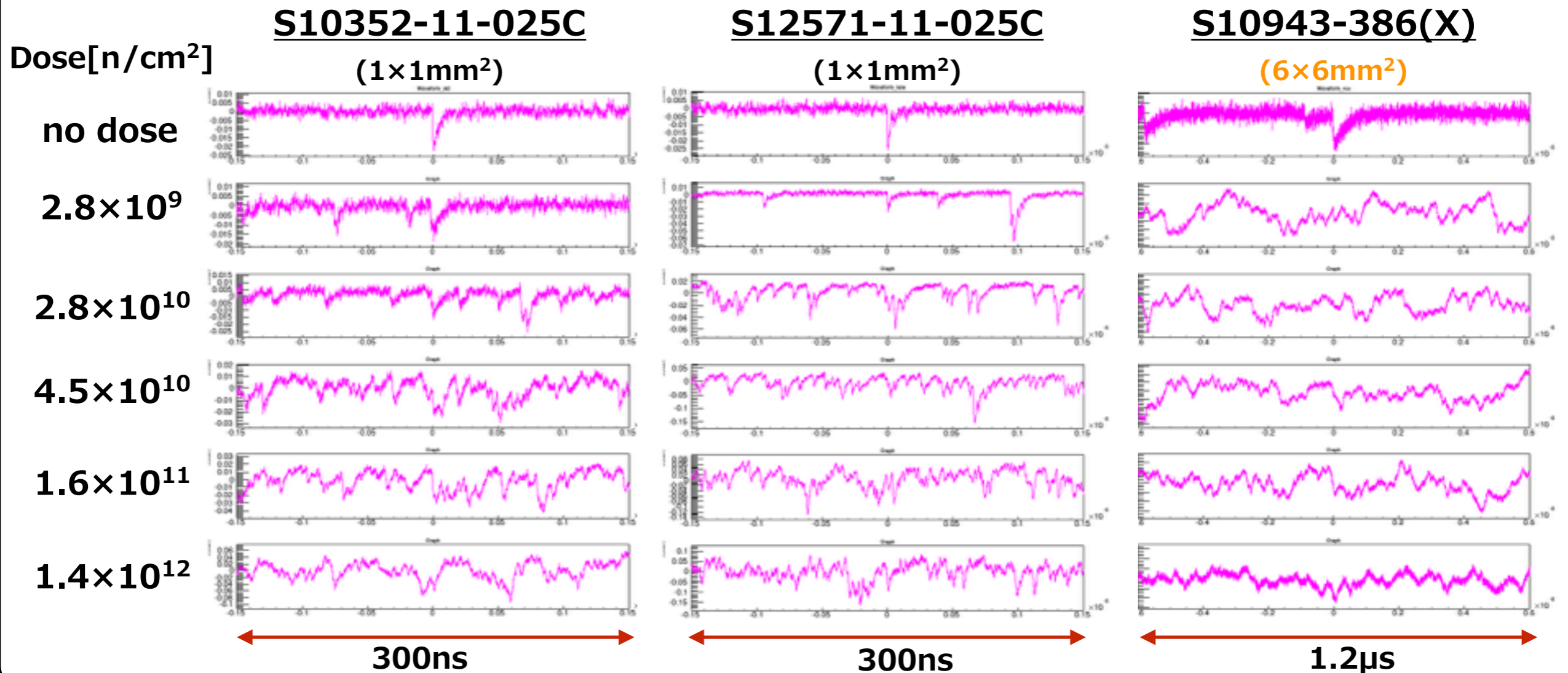
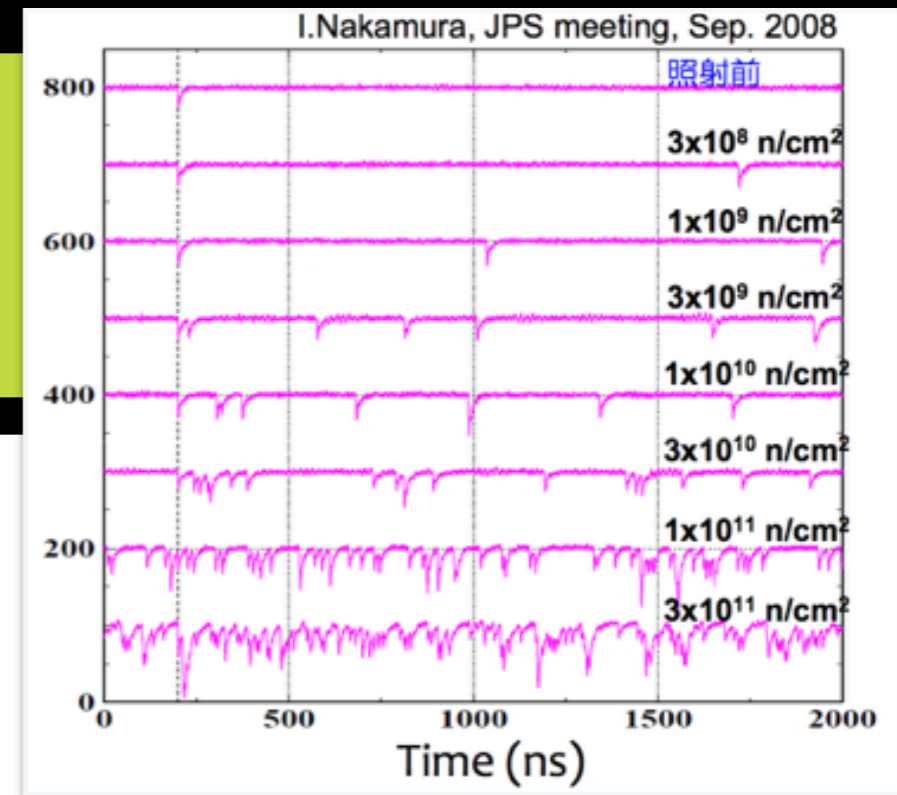
- Total fluence [n/cm^2]

- 2.8×10^9 , 2.8×10^{10} , 4.5×10^{10} , 1.6×10^{11} , 1.4×10^{12}



Increase of Dark Noise

Increase of dark noise looks consistent with previous study



Increase of Dark Noise

- Measured dark count rate only for the minimum dose (2.8×10^9 n/cm²).
- Compared leakage current for higher dose

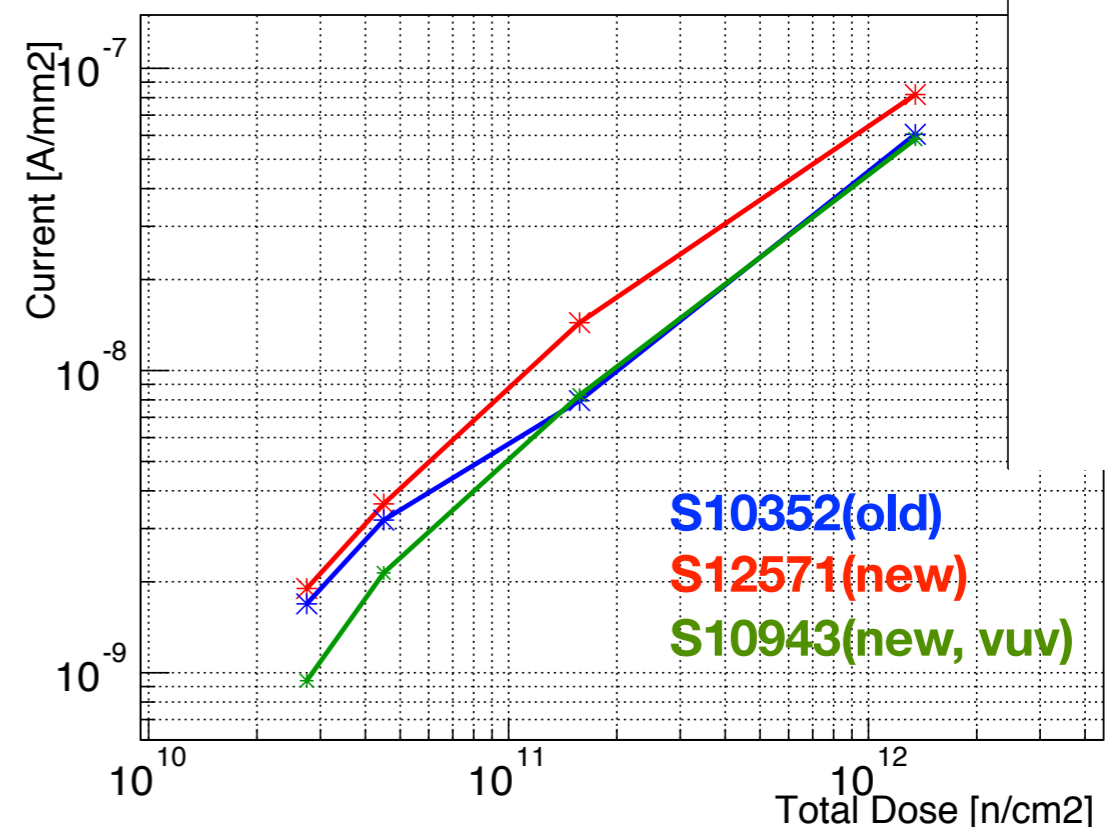
→ No significant difference of radiation hardness btw old and new versions

Dose @ 2.8×10^9 n/cm²

	DCR before irradiation [Hz]	DCR after irradiation [Hz]
sample 1 S10352 (old)	3.0×10^4 @V _{ov} =2.3V	4.8×10^6 @V _{ov} =2.3V
sample 2 S10352 (old)	2.6×10^4 @V _{ov} =2.3V	7.7×10^6 @V _{ov} =2.3V
sample 3 S12571 (new)	12.7×10^4 @V _{ov} =3.5V	15.6×10^6 @V _{ov} =3.5V
sample 4 S12571 (new)	7.2×10^4 @V _{ov} =3.5V	14.3×10^6 @V _{ov} =3.5V

N.B. different V_{ov} for old and new

Leakage current (@V < V_{bd})



Gamma Irradiation Test

- Co-60 (16TBq) at JAEA Takasaki

- Irradiated samples

- MPPC (S12571-11-025C)

- 1×1mm², 25μm-pixel
- Suppression on after-pulsing only, No suppression on cross-talk

- MPPC (S10943-3186(X))

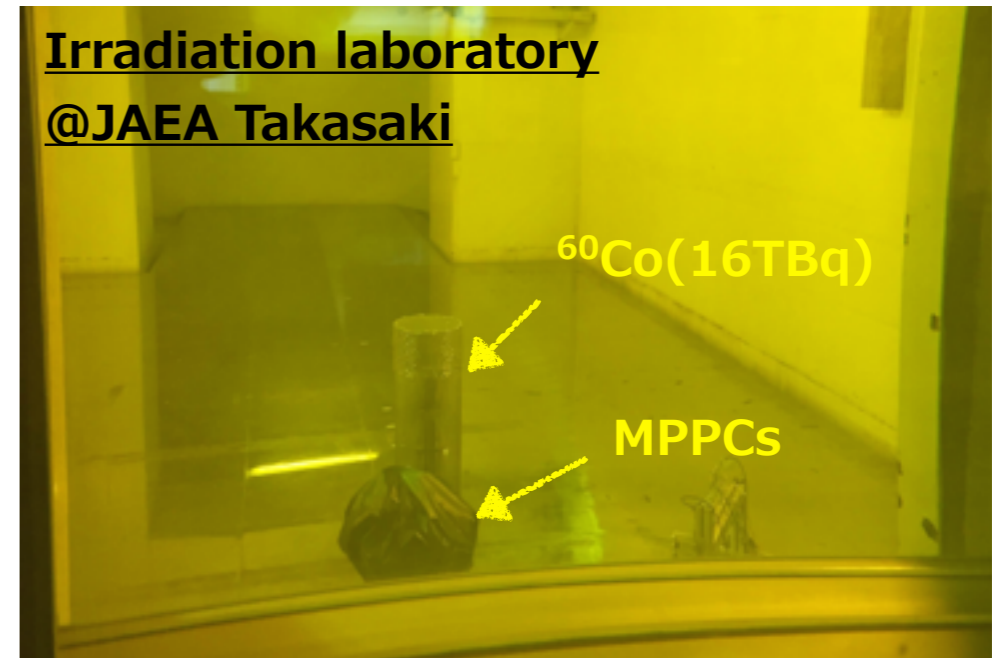
- 6×6mm², 50μm-pixel
- VUV-sensitive, developed for MEG
- Suppression on after-pulsing only, No suppression on cross-talk

- Compared btw only recent MPPCs (with after-pulsing suppression)

- Material type of insulation layer is different for S10943-3186(X) (VUV-sensitive).

- Dose conditions

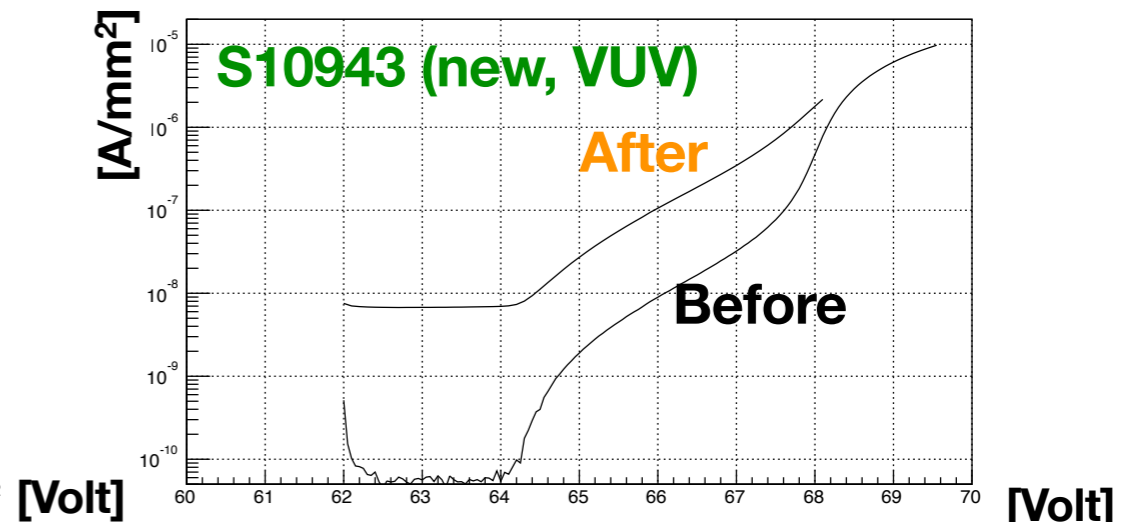
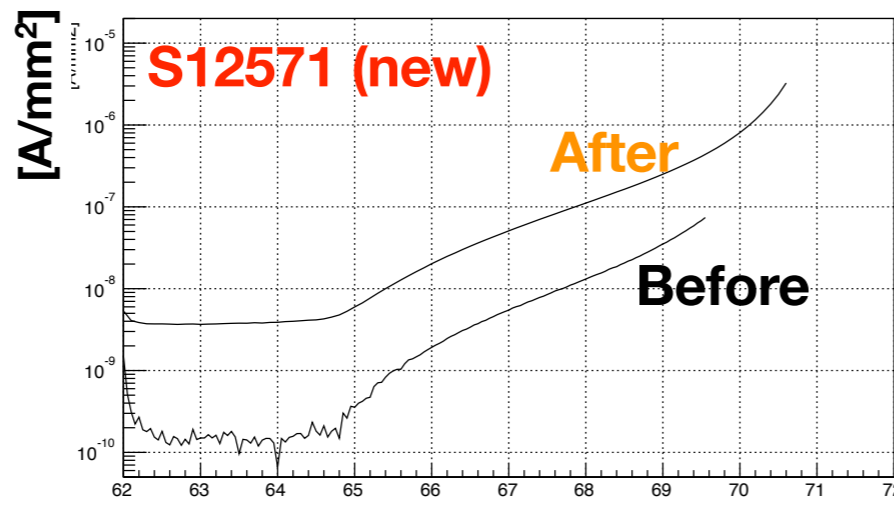
- 1.4kGy, 4.1kGy



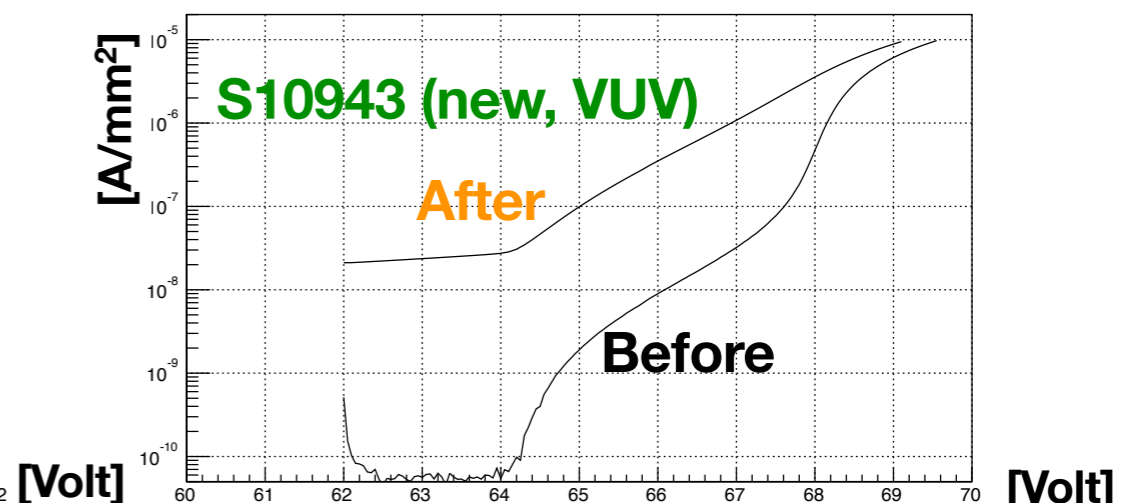
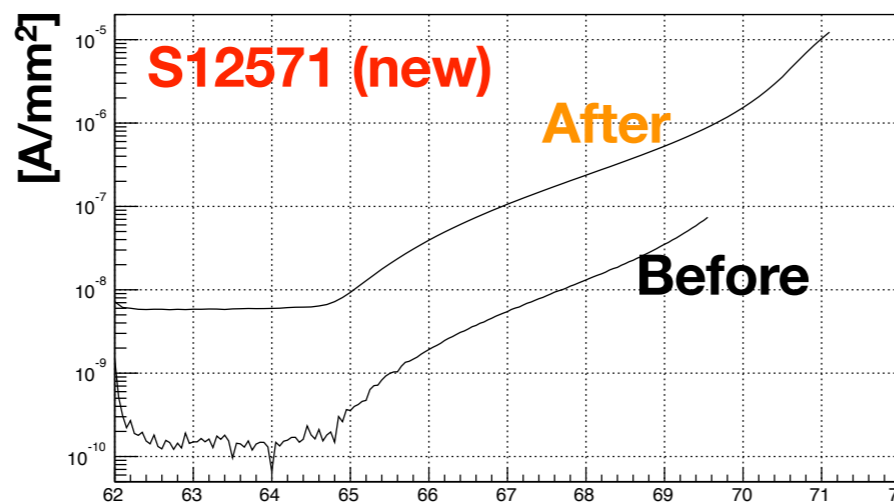
Gamma Irradiation Test

- Compared increase of leakage current after irradiation

1.4kGy →



4.1kGy →



- Increase of leakage current ~ ×10 @ 1.4kGy
- No significance difference in increase of leakage current btw S12571 and S10943

Next Steps for Radiation Hardness Study

- **Extended test of neutron irradiation is planned.**
 - Neutrons from reactor
 - Research reactor TRIGA at LENA, Pavia
- **Items to be tested.**
 - **SiPMs**
 - Most recent MPPC (with suppression on both afterpulsing and crosstalk)
 - VUV-MPPC
 - SiPM from FBK-AdvanSiD
 - Radiation hardness of candidate materials of scintillator (PVT, PS, MS)

Summary

- **Scintillator material study**

- Optimisation of scintillator material especially for PS/MS which can be produced with injection molding.
- Test production has been performed for PS-base scintillator with different fluorescent concentrations

- **New AHCAL tile design**

- Simulation study to investigate effect of cluster smearing is ongoing.
 - Implementation in digitisation task is completed.
- Optimisation of coupling btw tile and SiPM to maximise light yield and to minimise light leakage to neighbouring tile

- **Radiation hardness study**

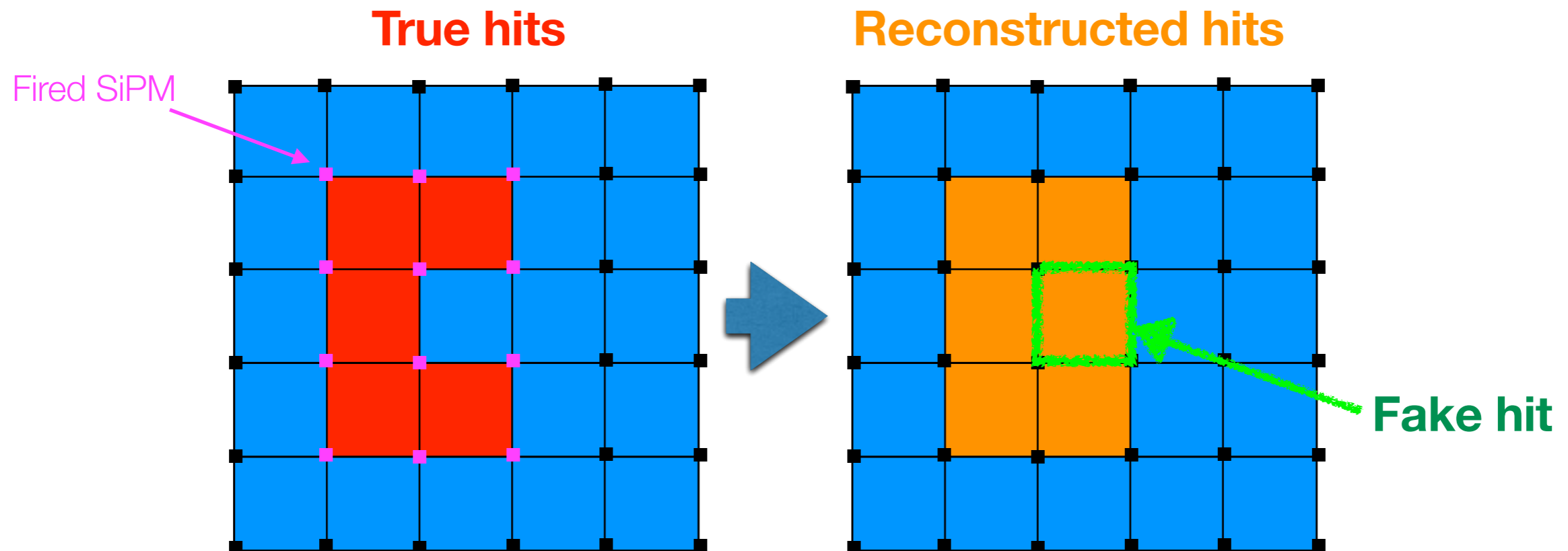
- No significant difference for recent version of MPPC (with after-pulsing suppression)
- Further study is planned using reactor neutrons.

Backup

How It Works

- **Reconstruction of cell hit and cell charge**

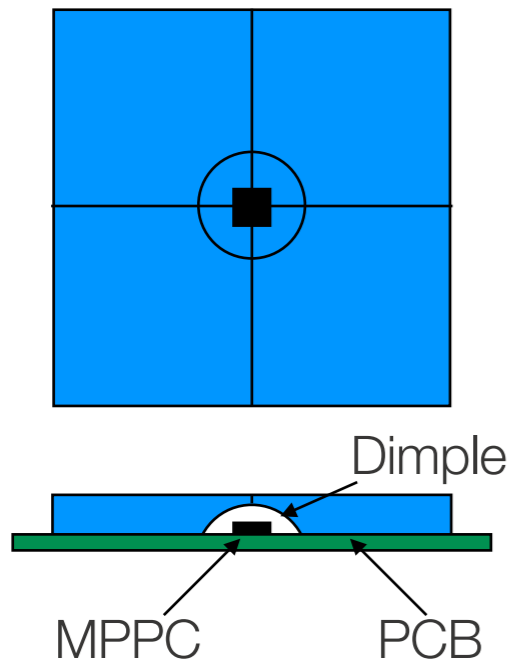
- Cell hit is defined by taking a coincidence on four SiPMs belonging to the cell.
- Cell charge is reconstructed by
 - Summing up charges for four SiPMs
 - If SiPM is shared by adjacent cell hits, SiPM charge is split to hit cells.



Possible Implementation

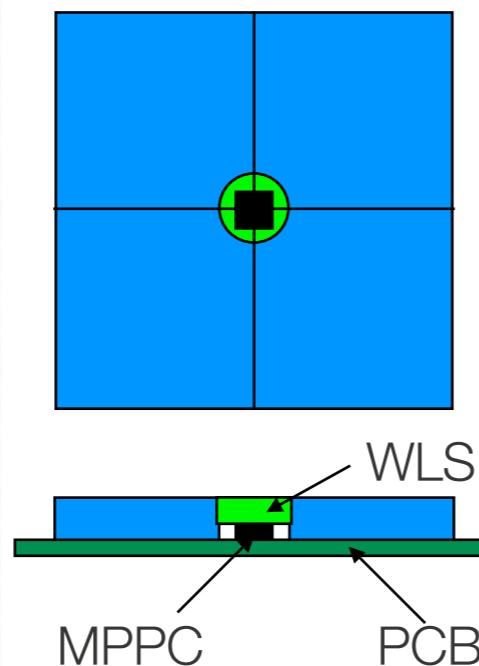
- Possible optical coupling of SiPM + Scintillator at cell vertex

Dimple at vertex

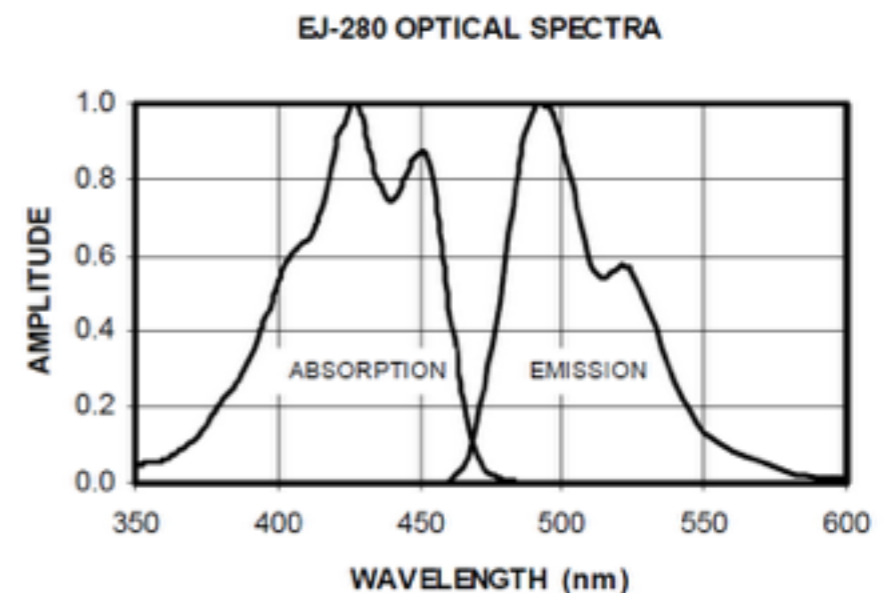


- Easier assembly
- Larger cross-talk?

Wavelength shifter (WLS) at vertex



- Complicated assembly
- Less cross-talk?
- Higher light yield?
- Dead region (~1%)

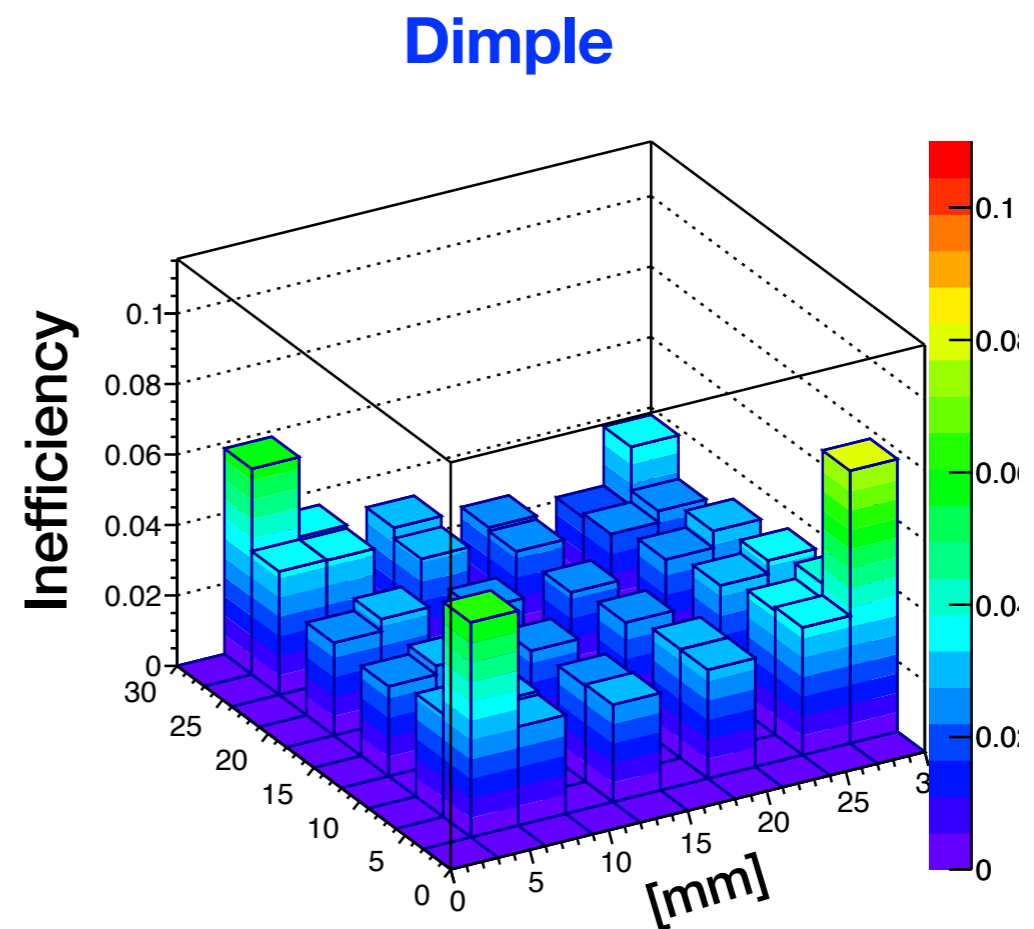
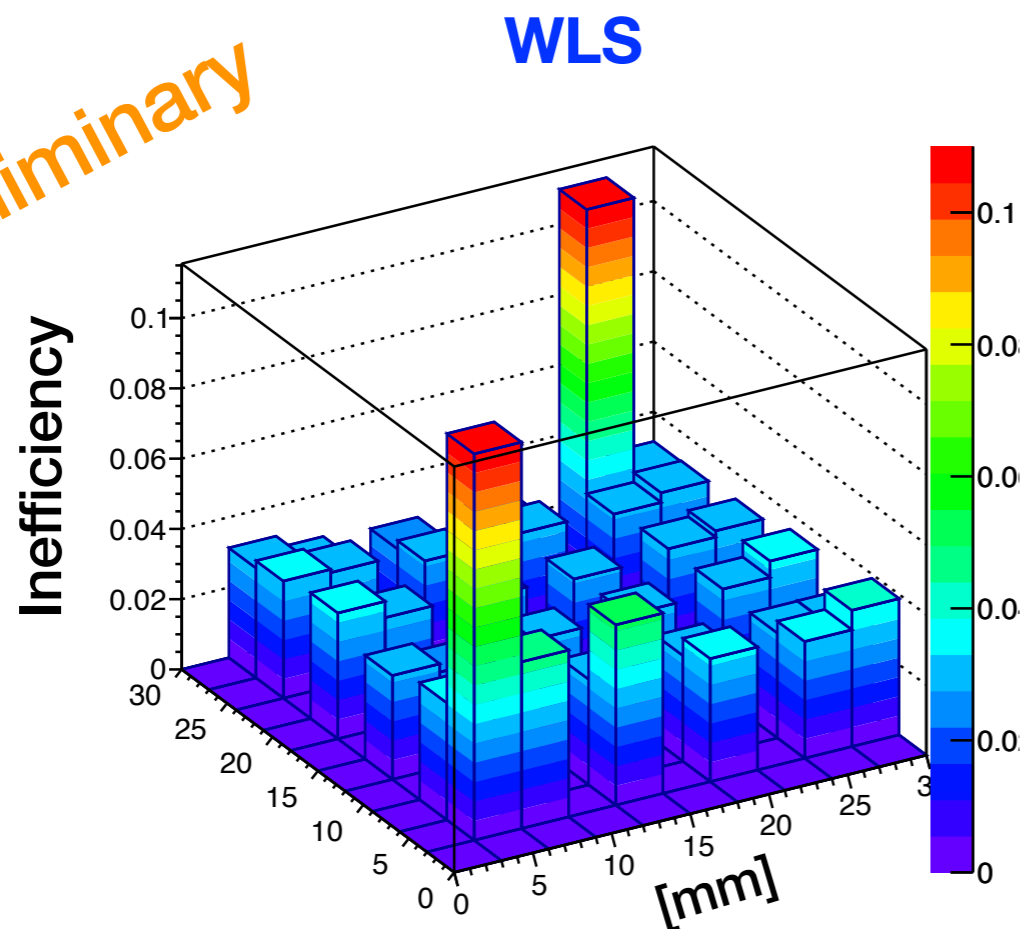


no absorption (and emission) of light from WLS at neighbouring cell

Inefficiency

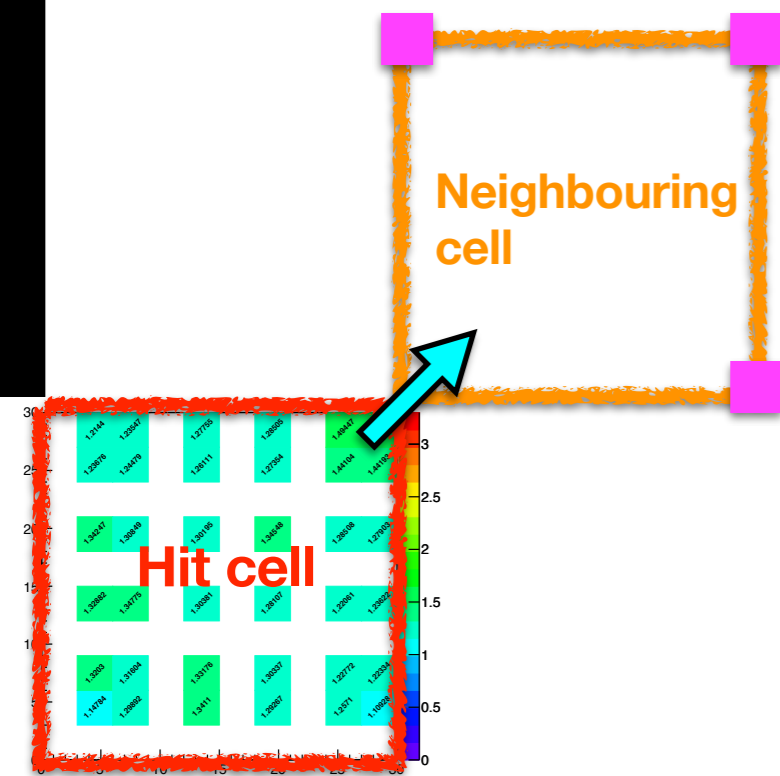
- Small chance of $N_{pe}=0$ at each SiPM if light yield is moderate. No hit is defined when taking a coincidence in this case. → inefficiency!
- Measured inefficiency ~ a few %
- Can be mitigated with improvement of light yield or higher threshold for coincidence. Note that optical coupling is not optimised yet.

Preliminary

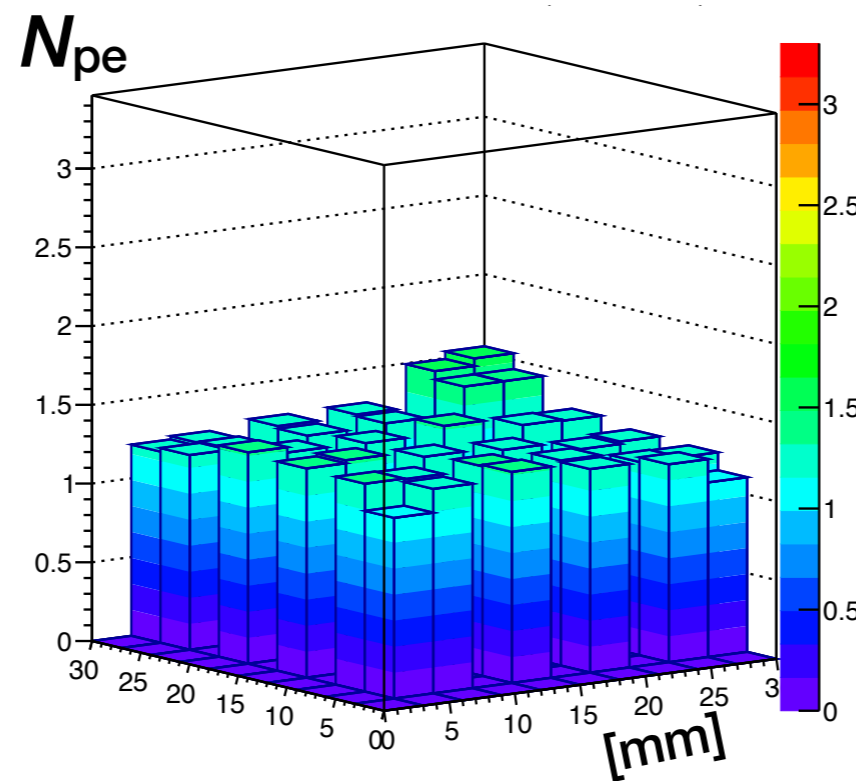


Cross-talk (Dimple)

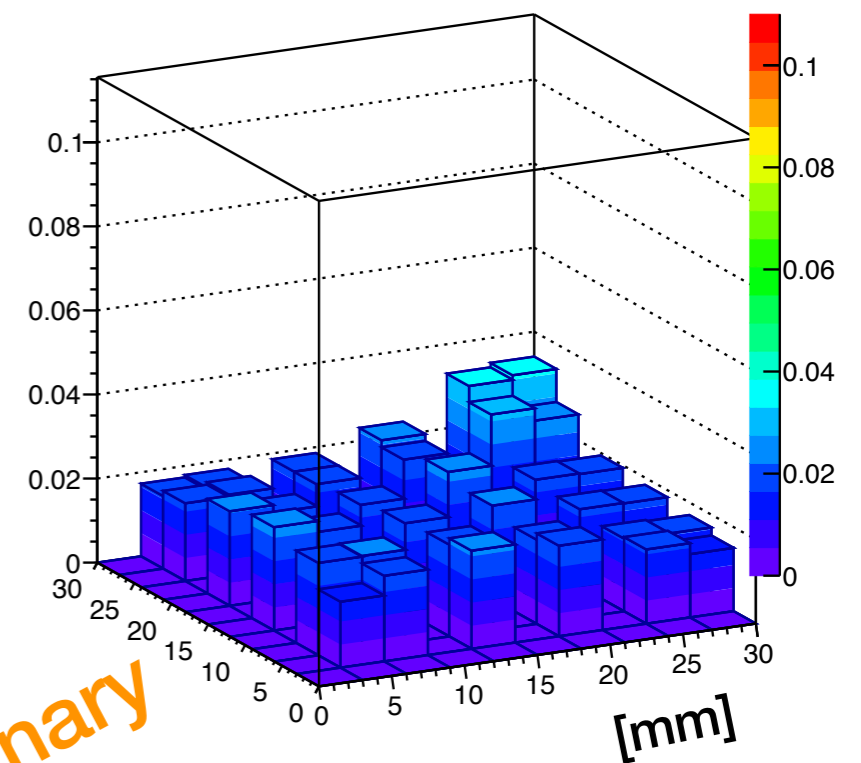
- Light leakage from hit cell to neighbouring cell was measured.
 - Sum of # of p.e. detected at three SiPMs in neighbouring cell **~1 p.e.**
 - Probability of fake hit at neighbouring cell triggered by light leakage (when taking quad coincidence) **~2%**



Average N_{pe}



Prob. of fake hit



Preliminary